AUTOMOTIVI GRADI

FREE



Vishay General Semiconductor

Surface-Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



SMB (DO-214AA)



PRIMARY CHARACTERISTICS					
V_{BR}	12 V to 51 V				
V_{WM}	10.2 V to 43.6 V				
P _{PPM}	1500 W				
T _J max.	185 °C				
Polarity	Unidirectional				
Package	SMB (DO-214AA)				

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lightning on ICs, MOSFET, signal lines of sensor units for automotive.

FEATURES

- Junction passivation optimized design passivated anisotropic rectifier technology
- T_J = 185 °C capability suitable for high reliability and automotive requirement
- 1500 W peak pulse power capability with a 10/1000 μs waveform
- Unidirectional
- · Excellent clamping capability
- · Very fast response time
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

MECHANICAL DATA

Case: SMB (DO-214AA)

Molding compound meets UL 94 V-0 flammability rating

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HM3 suffix meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	VALUE	UNIT				
Peak pulse power dissipation with a 10/1000 µs waveform (fig.1) (1)	P _{PPM}	1500	W				
Peak pulse current with a 10/1000 µs waveform (fig.3) (1)	I _{PPM}	See table next page	Α				
Operating junction and storage temperature range	T _J , T _{STG}	-65 to +185	°C				

Note

(1) Non-repetitive current pulse, per fig.3 and derated above T_A = 25 °C per fig.2



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C, unless otherwise noted)											
DEVICE MARKING CODE		BREAKDOWN VOLTAGE V _{BR} ⁽¹⁾ AT I _T (V)			STAND-OFF VOLTAGE V _{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM} I _R	MAXIMUM REVERSE LEAKAGE AT V _{WM} T _J = 150 °C I _D	MAXIMUM PEAK PULSE SURGE CURRENT	MAXIMUM CLAMPING VOLTAGE AT I _{PPM} V _C	TYPICAL TEMP. COEFFICIENT OF V _{BR} ⁽²⁾ αT	
		MIN.	NOM.	MAX.			(μΑ)	(μ A)	(A)	(V)	(%/°C)
T15B12A	KX5	11.4	12.0	12.6	1.0	10.2	2.0	12.0	91.2	17.0	0.070
T15B13A	KZ5	12.4	13.0	13.7	1.0	11.1	2.0	10.0	83.8	18.5	0.072
T15B15A	LG5	14.3	15.0	15.8	1.0	12.8	1.0	10.0	73.1	21.2	0.076
T15B16A	LK5	15.2	16.0	16.8	1.0	13.6	1.0	10.0	68.9	22.5	0.078
T15B18A	LM5	17.1	18.0	18.9	1.0	15.3	1.0	10.0	60.8	25.5	0.080
T15B20A	LR5	19.0	20.0	21.0	1.0	17.1	1.0	10.0	56.0	27.7	0.082
T15B22A	LS5	20.9	22.0	23.1	1.0	18.8	1.0	10.0	50.7	30.6	0.084
T15B24A	LV5	22.8	24.0	25.2	1.0	20.5	1.0	10.0	46.7	33.2	0.085
T15B27A	LW5	25.7	27.0	28.4	1.0	23.1	1.0	10.0	41.3	37.5	0.087
T15B30A	ME5	28.5	30.0	31.5	1.0	25.6	1.0	10.0	37.4	41.4	0.088
T15B33A	MG5	31.4	33.0	34.7	1.0	28.2	1.0	10.0	33.9	45.7	0.089
T15B36A	MJ5	34.2	36.0	37.8	1.0	30.8	1.0	15.0	31.1	49.9	0.090
T15B39A	MM5	37.1	39.0	41.0	1.0	33.3	1.0	15.0	28.8	53.9	0.091
T15B43A	MN5	40.9	43.0	45.2	1.0	36.8	1.0	20.0	26.1	59.3	0.092
T15B47A	MR5	44.7	47.0	49.4	1.0	40.2	1.0	20.0	23.9	64.8	0.092
T15B51A	MT5	48.5	51.0	53.6	1.0	43.6	1.0	20.0	22.1	70.1	0.093

Notes

⁽³⁾ All terms and symbols are consistent with ANSI/IEEE C62.35

IMMUNITY TO STATIC ELECTRICAL DISCHARGE TO THE FOLLOWING STANDARDS ($T_A = 25~^{\circ}\text{C}$ unless otherwise noted)						
STANDARD	TEST TYPE	TEST CONDITIONS	SYMBOL	VALUE		
IEC 61000-4-2	Contact discharge	C = 150 pF, R = 330 Ω	ESD	30 kV		
120 01000-4-2	Air discharge	$C = 130 \text{ pr}, N = 330 \Omega$	LSD	30 kV		

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
T15B12AHM3/H ⁽¹⁾	0.107	Н	750	7" diameter plastic tape and reel			
T15B12AHM3/I (1)	0.107	I	3200	13" diameter plastic tape and reel			

Note

(1) AEC-Q101 qualified

 $^{^{(1)}}$ V_{BR} measured after I_T applied for 300 μs , I_T = square wave pulse or equivalent

To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at $T_J = V_{BR}$ at 25 °C x (1 + α T x (T_J - 25))

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C, unless otherwise noted)

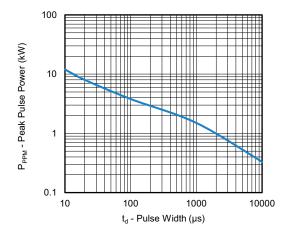


Fig. 1 - Peak Pulse Power Rating Curve

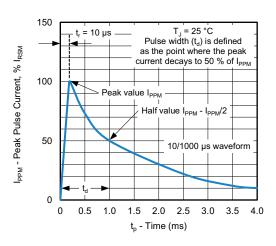


Fig. 3 - Pulse Waveform

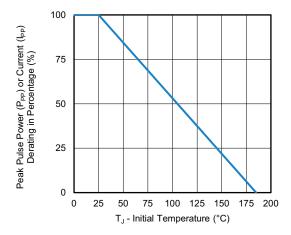


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

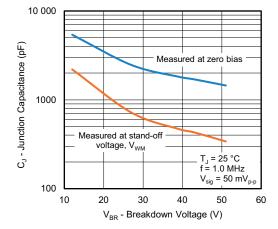


Fig. 4 - Typical Junction Capacitance

Note

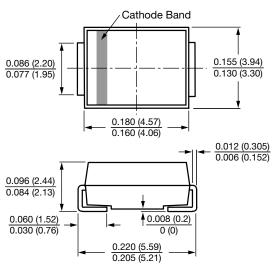
• Fig.1, power calculations is based on I_{PPM} times defined maximum clamping voltage by pulse width



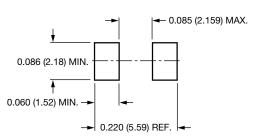
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

SMB (DO-214AA)



Mounting Pad Layout





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